# NCP3712ASN, SZNCP3712ASN

# **Over Voltage Protected High Side Switch**

This switch is primarily intended to protect loads from transients by isolating the load from the transient energy rather than absorbing it.

### Features

- Capable of Switching Loads of up to 200 mA without External Rboost
- Switch Shuts Off in Response to an Over Voltage Input Transient
- Features Active Turn Off for Fast Input Transient Protection
- Flexible Over Voltage Protection Threshold Set with External Zener
- Automatic Recovery after Transient Decays Below Threshold
- Withstands Input Transients up to 105 V Peak
- Guaranteed Off State with Enbl Input
- ESD Resistant in Accordance with the 2000 V Human Body Model
- Extremely Low Saturation Voltage
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb–Free Devices

#### **Applications Include:**

- High Voltage Transient Isolation
- Power Switching to Electronic Modules
- DC Power Distribution in Line Operated Equipment
- Buffering Sensitive Circuits from Poorly Regulated Power Supplies
- Pre-conditioning of Voltage Regulator Input Voltage

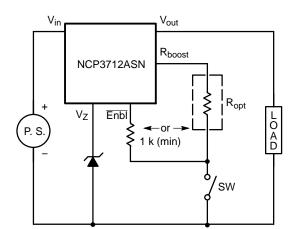
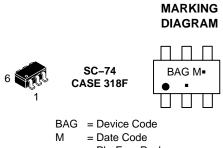


Figure 1. Typical Application Circuit

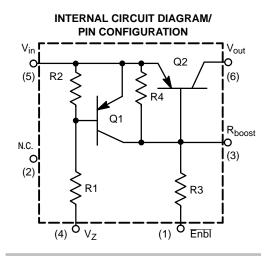


# **ON Semiconductor®**

http://onsemi.com



= Pb-Free Package
(Note: Microdot may be in either location)



#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NCP3712ASNT1G	SC–74	3000 / Tape &
SZNCP3712ASNT1G	(Pb–Free)	Reel
NCP3712ASNT3G	SC–74	10,000 / Tape &
SZNCP3712ASNT3G	(Pb–Free)	Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted) (Note 1)

Rating	Symbol	Value	Unit
Input-to-Output Voltage	V <sub>io</sub>	105	V
Reverse Input-to-Vz. Voltage	V <sub>in(rev)</sub>	-9.0	V
Reverse Input-to-Rboost Voltage	V <sub>in(rev)</sub>	-5.0	V
Output Load Current – Continuous	l <sub>load</sub>	-300	mA
Enbl Input Current – Continuous	l <sub>enbl</sub>	5.0	mA
Vz Input Current – Continuous	Ι <sub>z</sub>	3.0	mA
Rboost Input Current – Continuous	I <sub>boost</sub>	10	mA
Junction Temperature	TJ	125	°C
Operating Ambient Temperature Range	T <sub>A</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C
Device Power Dissipation (Minimum Footprint)	PD	300	mW
Derate Above 25°C	-	2.4	mW/°C
Latchup Performance: Positiv Negativ	Latonup	200 200	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 This device contains ESD protection and exceeds the following tests: Human Body Model 1500 V per MIL–STD–883, Method 3015. Machine Model Method 150 V.

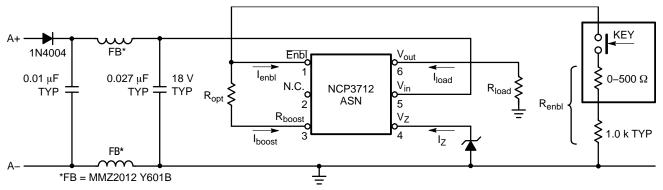
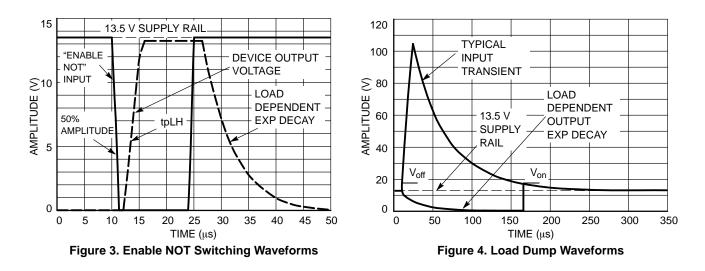


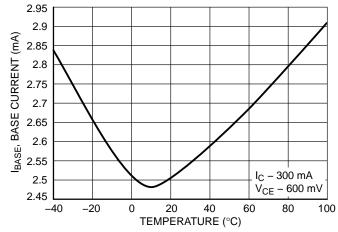
Figure 2. Typical Applications Circuit for Load Dump Transient Protection



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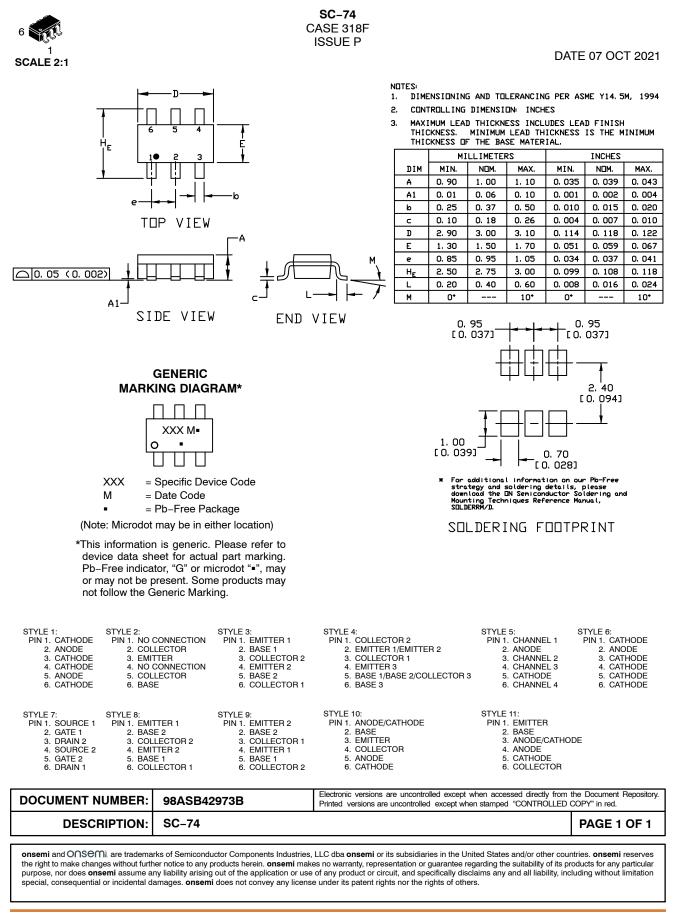
## **ELECTRICAL CHARACTERISTICS** ( $V_{in}$ = 12.5 $V_{DC}$ Ref to Gnd, $T_A$ = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					I.
Input–Output Breakdown Voltage (@ I <sub>out</sub> = 200 μA)	V <sub>(BRio)</sub>	105	_	_	Vdc
Output Reverse Breakdown Voltage (@ I <sub>out</sub> = -1.0 mA Pulse)	V <sub>(-BRout)</sub>	-	-0.7	_	Vdc
Output Leakage Current $(V_{in} = V_{enbl} = 30 \text{ V}, T_A = 25^{\circ}\text{C})$	I <sub>load(off)</sub>	_	-	-100	μAdc
Guaranteed "Off" State "ENBL NOT" Voltage $(I_O \le 100 \ \mu A)$	V <sub>enbl(off)</sub>	13	_	_	Vdc
Required "Off" State $I_z$ Current ( $R_{load} = 100 \Omega$ )	I <sub>z(off)</sub>	150	-	-	μAdc
$V_{in(off)}$ (V <sub>z</sub> = 16 V, I <sub>load</sub> = 100 mA, R <sub>enbl</sub> = 1500 $\Omega$ )	V <sub>off</sub>	15.5	-	18.7	Vdc
ON CHARACTERISTICS					
Input–Output On Voltage ( $I_o = 100 \text{ mA}, I_{enbl} = -3.0 \text{ mA}$ )	V <sub>io(on)</sub>	_	0.2	0.5	Vdc
$\begin{array}{l} \text{Output Load Current} & \text{Continuous} \\ (I_{enbl} = -3.0 \text{ mA}, \text{V}_{io(on)} = 0.5 \text{ Vdc}) \\ (I_{boost} = -9.0 \text{ mA}, \text{V}_{io(on)} = 0.5 \text{ Vdc}) \\ (I_{boost} = -9.0 \text{ mA}, \text{V}_{io(on)} = 0.6 \text{ Vdc}) \end{array}$	l <sub>o(on)</sub>	_ _ _	_ _ _	-200 -200 -300	mAdc
$V_{in(on)}$ (V <sub>z</sub> = 16 V, I <sub>load</sub> = 100 mA, R <sub>enbl</sub> = 1500 $\Omega$ )	V <sub>on</sub>	8.5	_	10.5	Vdc
"ENBL NOT" Input Current $(I_0 = 100 \text{ mA}, V_{io(on)} = 0.35 \text{ Vdc}, R_{enbl} = 1500 \Omega)$	l <sub>enbl</sub>	-	_	-1.0	mAdc
SWITCHING CHARACTERISTICS	·		•		
Propagation Delay Time: Hi to Lo Prop Delay; Fig. 3 (V <sub>in</sub> = V <sub>enbl</sub> = 13.5 V) Lo to Hi Prop Delay; Fig. 3 (V <sub>in</sub> = 13.5 V, V <sub>enbl</sub> = 0 V)	t <sub>PHL</sub> t <sub>PLH</sub>		1.5 1.5		μS
Transition Times: Fall Time; Fig. 4 ( $V_{in} = V_{enbl} = 13.5 V$ ) Rise Time; Fig. 4 ( $V_{in} = V_{enbl} = 0 V$ )	t <sub>f</sub> t <sub>r</sub>		75 400		ηS
INTERNAL RESISTORS		•			•
Input Leakage Resistor	R2	7.0	10	13	kΩ
Input Resistor	R1	3.3	4.7	6.1	kΩ
Output Leakage Resistor	R4	1.4	2.4	3.2	kΩ
Enable Input Resistor	R3	1.4	2.4	3.2	kΩ





# onsemi



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